

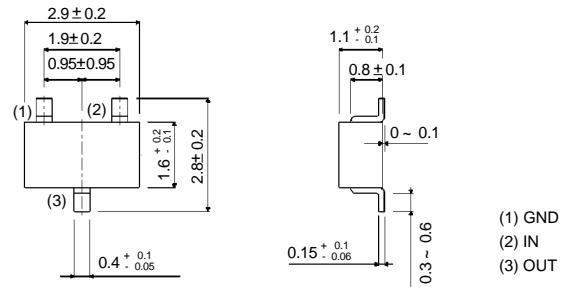
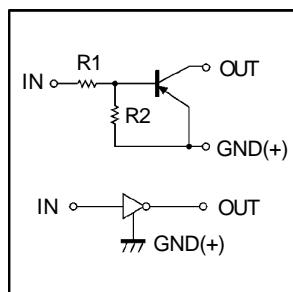
Digital transistors (built-in resistors)

- **Features**

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thinfilm resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/ off conditions need to be set for operation, making device design easy.

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- **Equivalent circuit**



All terminals have same dimensions

EIAJ: SC—59

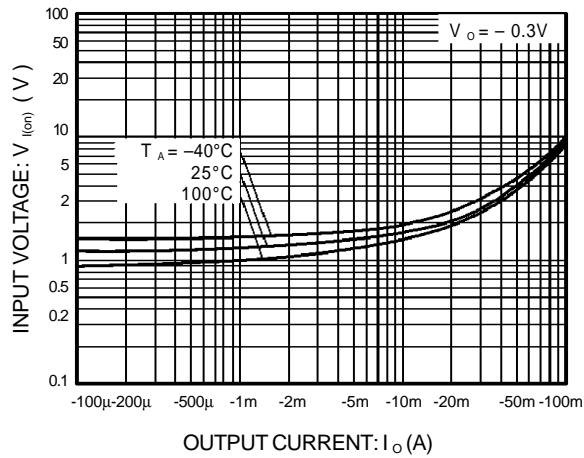
- Absolute maximum ratings($T_a=25^\circ\text{C}$)

Parameter	symbol	limits		unit
Supply voltage	V_{cc}	-50		V
Input voltage	V_{in}	-12~+10		V
Output current	I_o	-100		mA
	$I_{C(\text{Max.})}$	-100		
Power dissipation	P_d	200		mW
Junction temperature	T_j	150		°C
Storage temperature	T_{stg}	-55~+150		°C

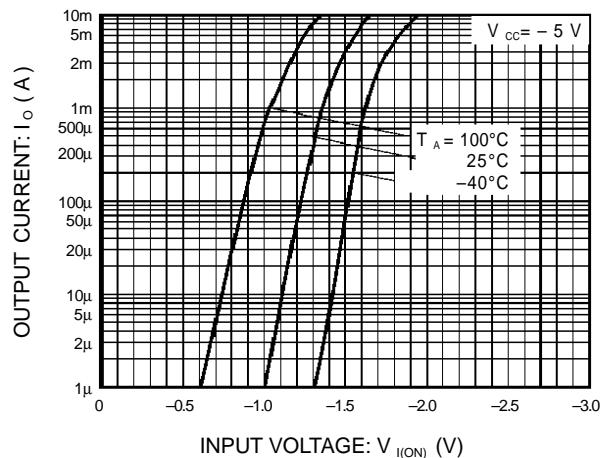
- Electrical characteristics($T_a=25^\circ\text{C}$)

Parameter	symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	$V_{I(\text{off})}$	—	—	-0.5	V	$V_{cc}=-5\text{V}, I_o=-100\mu\text{A}$
	$V_{I(\text{on})}$	-3	—	—		$V_o=-0.3\text{V}, I_o=-20\text{mA}$
Output Voltage	$V_{O(\text{on})}$	—	-0.1	-0.3	V	$I_o/I_i=-10\text{mA}/-0.5\text{mA}$
Input current	I_i	—	—	-3.8	mA	$V_i=-5\text{V}$
Output current	$I_{O(\text{off})}$	—	—	-0.5	μA	$V_{cc}=-50\text{V}, V_i=0\text{V}$
DC current gain	G_i	20	—	—	—	$V_o=-5\text{V}, I_o=-20\text{mA}$
Input resistance	R_1	1.54	2.2	2.86	KΩ	—
Resistance ratio	R_2/R_1	0.8	1	1.2	—	—
Transition frequency	f_T	—	250	—	MHz	$V_{ce}=-10\text{V}, I_e=5\text{mA}, f=100\text{MHz}^*$

*Transition frequency of the device

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ELECTRICAL CHARACTERISTIC CURVES


**Figure 1. Input voltage vs.output current
(ON characteristics)**



**Figure 2. Output current vs.input voltage
(OFF characteristics)**

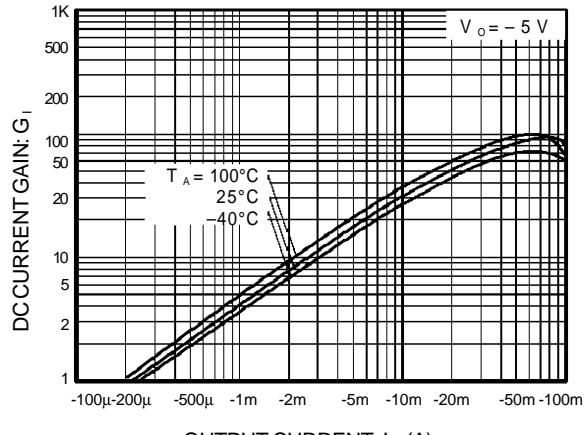


Figure 3. DC current gain vs.output current

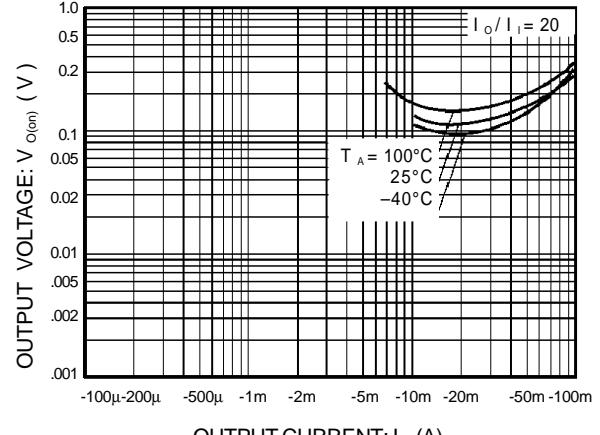


Figure 4. Output voltage vs.output current